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## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. <sup>1</sup>	Document Number			
		Number	Kind Code <sup>2</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
/S.H./		US 2002/0155682	Al	10-24-2002	T. Shibata, et al.
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Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document			Publication Date	Name of Patentee or	
		Country Code <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>5</sup> (if known)	MM-DD-YYYY	Applicant of Cited Document	Translation <sup>6</sup>
7S.H.7		EP	0732754	A2	09-18-1996	TOYODA GOSEI CO., LTD.	
		<u> </u>					

Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.				
/S.H./		T. S. Zheleva, et al., "PENDEO-EPITAXY - A NEW APPROACH FOR LATERAL GROWTH OF GALLIUM NITRIDE STRUCTURES", MRS Internet J. Nitride Semicond. Res. 4S1, G3.38 (1999)				

	/Shouviana Hu/		03/04/2008	
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